

# **PRODUCT RELIABILITY REPORT**

**Product: MPQ7225A-AEC1**

**Reliability Department  
Monolithic Power Systems  
79 Great Oaks Boulevard  
San Jose, CA 95119  
Tel: 408-826-0600  
Fax: 408-826-0601**

## 1. Device Information

Product:	MPQ7225A-AEC1
Package:	32-PIN QFN (5mm×6mm)
Process Technology:	BCD
Report Date:	10/27/2023

## 2. Summary of Test Results

Test	#	Test Condition	Lot# or Date Code	Test Results (S.S./Rej)	Comment
Preconditioning, prior to THB/HAST, AC/UHST, TC, HTSL and PTC	A1	J-STD-020 Reflow: $T_p \geq 260^\circ\text{C}$ , $t_p \geq 30\text{sec}$ , 3×reflows	2301 2307 2320	308/0 308/0 308/0	MSL=2
Temperature Humidity Bias (THB)	A2	JESD22-A101, @85°C/85%RH static bias at $V_{inmax}$ for 1000 hours or equivalent	2301 2307 2320	77/0 77/0 77/0	
Unbiased Autoclave (AC)	A3	JESD22-A102, @121°C/100%RH for 168 hours or equivalent	2301 2307 2320	77/0 77/0 77/0	
Temperature Cycling (TC)	A4	JESD22-A104, from - 65°C to 150°C for 1000 cycles or equivalent	2301 2307 2320	77/0 77/0 77/0	
Power Temperature Cycling (PTC)	A5	JESD22-A105, from - 40°C to 125°C for 1000 cycles.	EP970502	45/0	
High Temperature Storage Life (HTSL)	A6	JESD22-A103, @150°C for 1000 hours	2301 2307 2320	77/0 77/0 77/0	
High Temperature Operating Life (HTOL)	B1	JESD22-A108, @ $T_j = 150^\circ\text{C}$ for 1000 hours or equivalent	EP970502 EPA817 EPA844	77/0 77/0 77/0	
Early Life Failure Rate (ELFR)	B2	AEC-Q100-008, @ $T_j = 150^\circ\text{C}$ for 48 hours, or equivalent	EP970502 EPA817 EPA844	800/0 800/0 800/0	

Electrostatic Discharge Human Body Model (HBM)	E2	AEC-Q100-002	EPA98101	3/0	>2000V
Electrostatic Discharge Charged Device Model (CDM)	E3	AEC-Q100-011	EPA98101	3/0	>750V
Latch-up (LU)	E4	AEC-Q100-004	EPA98101	6/0	>+/-100mA & >1.5Vccmax

### **3. Failure Rate Calculation**

Sample Size:	6590
Rejects:	0
Activation Energy (eV):	0.7
Equivalent Device Hours:	$5.14 \times 10^8$ Hours
Failure Rate (FIT@60%CL):	1.8 FIT
MTBF (years):	64,129 Years

### **Revision / Update History**

Revision	Reason for Change	Date	Rel Engineer
1.0	Initial release	November 2023	Ramon Lei

## **Appendix: Description of Reliability Test and Failure Rate Calculation**

### **High Temperature Operating Life Test**

**Purpose:** This test is a worst-case life test that checks the integrity of the product. The high temperature testing is used for acceleration of any potential failures over time. The calculation for failure rate (FIT) using the operating ambient temperature is done using the Arrhenius equation.

**Condition:**  $T_j = 150^{\circ}\text{C}$  @ Vinmax

**Pass Criteria:** All units must pass the min/max limits of the datasheet.

### **ESD Test**

**Purpose:** The purpose of the ESD test is to guarantee that the device can withstand electrostatic voltages during handling.

**Condition:** Human Body Model and Charged Device Model

**Pass Criteria:** ESD Testing on every pin. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **IC Latch-Up Test**

**Purpose:** The purpose of this specification is to establish a method for determining IC latch-up characteristics and to define latch-up failure criteria. Latch-up characteristics are extremely important in determining product reliability and minimizing No Trouble Found (NTF) and Electrical Overstress (EOS) failures due to latch-up.

**Condition:** Voltage and current injection

**Pass criteria:** All pins with the exception of “no connect” pins and timing related pins, shall be latch-up tested. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices**

**Purpose:** The purpose of this standard is to identify the classification level of nonhermetic solid state surface mount devices (SMDs) that are sensitive to moisture-induced stress so that they can be properly packaged, stored, and handled to avoid damage during assembly solder reflow attachment and/or repair operations.

**Condition:** Bake + moisture sock + 3X reflow at  $260^{\circ}\text{C}$

**Pass criteria:** All units must pass the min/max limits of the datasheet

### **Accelerated Moisture Resistance- Unbiased Autoclave**

**Purpose:** To check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:**  $121^{\circ}\text{C}/15\text{psig}/100\% \text{ RH}$  (no bias)

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Temperature Cycle Test**

**Purpose:** This test is used to evaluate the die attach integrity and bond integrity. This is similar to the Thermal Shock test, but can generate different failure modes due to the longer dwell time and gradual temperature change.

**Condition:**  $-65^{\circ}\text{C}$  to  $150^{\circ}\text{C}$

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Steady State Temperature Humidity Bias Life Test**

**Purpose:** This is to check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:** 85% RH at  $85^{\circ}\text{C}$  with  $V_{in} = V_{inmax}$

**Pass Criteria:** All units must pass min/max limits of the datasheet

### Highly Accelerated Temperature and Humidity Stress Test

**Purpose:** This is an equivalent test to Steady State Temperature Humidity Bias Life test with different (higher) temperature stress condition.  
**Condition:** 85%RH at 130°C with Vin=Vinmax  
**Pass Criteria:** All units must pass min/max limits of the datasheet

### Failure Rate Calculation

The failure rate is gauged by a Failures-In-Time (FIT) based upon accelerated stress data. The unit for FIT is failure per billion device hour.

$$FIT\ Rate = \frac{(\chi^2/2) \times 10^9}{EDH}$$

Where

$\chi^2$  (Chi-Squared) is the goodness-of-fit test statistic at a specified level of confidence;  
 EDH= Equivalent Device Hours = AF × (Life test sample size) × (test duration);  
 AF= Acceleration Factor.

High Temperature Operating Life (HTOL) test is usually done under acceleration of temperature and voltage. The total number of failures from the stress test determines the chi-squared factor.

$$AF = AF_T \times AF_V$$

The Temperature Acceleration Factor  $AF_T$ :

$$AF_T = \exp\left(\frac{E_a}{K} \left( \frac{1}{T_{J(Use)}} - \frac{1}{T_{J(stress)}} \right)\right)$$

$T_{Juse}$  = Junction temp under typical operating conditions;  
 $T_{Jstress}$  = Junction temp under accelerated test conditions;  
 $E_a$  is Activation energy=0.7eV;  
 $K$ =Boltzmann's constant=8.62×10<sup>-5</sup> eV/K.

The voltage Acceleration Factor  $AF_V$ :

$$AF_V = e^{\beta \times [V_{stress} - V_{use}]}$$

$V_{use}$  = Gate voltage under typical operating conditions;  
 $V_{stress}$  = Gate voltage under accelerated test conditions;  
 $\beta$  = Voltage acceleration factor (in 1/Volts) and specified by technology.  
 Note: For calculation in the report,  $AF_V = 1$  for simplicity.

MTBF (Mean Time Between Failure) equals to 10<sup>9</sup>/FIT (in hours).